



# PNP SILICON PLANAR SWITCHING TRANSISTORS

2N2906A 2N2907A TO-18

## Switching And Linear Application DC to VHF Amplifier Applications

### ABSOLUTE MAXIMUM RATINGS

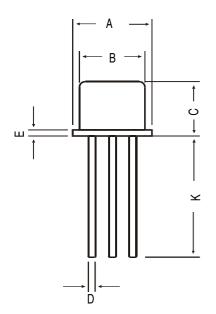
| DESCRIPTION  | SYMBOL   | 2N2906A, 07A  |                        |  | UNIT                          |  |
|--|--|---|------------------------|--|-------------------------------|--|
| Collector -Emitter Voltage   | VCEO   | 60  |                        |  | V                             |  |
| Collector -Base Voltage  | VCEO   | 60  |                        |  | v                             |  |
| Emitter -Base Voltage  | VEBO   | 5.0   |                        |  | V                             |  |
| Collector Current Continuous   | IC   | 600   |                        | •  |                               |  |
|  | PD   | 400   | mA<br>mM               |  |                               |  |
| Power Dissipation @Ta=25 degC  | FD   |   |                        |  | mW                            |  |
| Derate Above 25deg C   |  | 2.28  |                        | rnv  | V/deg C                       |  |
| @ Tc=25 degC   | PD   | 1.8   |                        | W  |                               |  |
| Derate Above 25deg C   | <b></b>  | 10.3  |                        | mW/deg C                                     |                               |  |
| Operating And Storage Junction   | Tj, Tstg   | - 65 to +200  |                        |  | deg C                         |  |
| Temperature Range  |  |   |                        |  |                               |  |
| ELECTRICAL CHARACTERISTICS (T  | a=25 deg C l   | Unless Otherwise Specified)   |                        |  |                               |  |
|  |  |   |                        |  |                               |  |
| DESCRIPTION  | SYMBOL   |   | VAL                    | LIE  |                               |  |
| DESCRIPTION  | SYMBOL   | TEST CONDITION  | VAL<br>MIN             |  |                               |  |
|  | SYMBOL<br>VCEO*  | TEST CONDITION  | VAL<br>MIN<br>60       | _UE<br>MAX<br>-                              | UNIT                          |  |
| Collector -Emitter Voltage   | VCEO*  |   | MIN                    | MAX  |                               |  |
| Collector -Emitter Voltage<br>Collector -Base Voltage  | VCEO*<br>VCBO  | IC=10mA,IB=0<br>IC=10uA.IE=0  | <b>MIN</b><br>60<br>60 | MAX  | V                             |  |
| Collector -Emitter Voltage<br>Collector -Base Voltage<br>Emitter-Base Voltage  | VCEO*  | IC=10mA,IB=0  | <b>MIN</b><br>60       | MAX  | V<br>V                        |  |
| Collector -Emitter Voltage<br>Collector -Base Voltage<br>Emitter-Base Voltage  | VCEO*<br>VCBO<br>VEBO  | IC=10mA,IB=0<br>IC=10uA.IE=0<br>IE=10uA, IC=0<br>VCB=50V, IE=0  | <b>MIN</b><br>60<br>60 | MAX<br>-<br>-<br>-                           | V<br>V<br>V                   |  |
| Collector -Emitter Voltage<br>Collector -Base Voltage<br>Emitter-Base Voltage  | VCEO*<br>VCBO<br>VEBO  | IC=10mA,IB=0<br>IC=10uA.IE=0<br>IE=10uA, IC=0<br>VCB=50V, IE=0<br>Ta=150 deg C  | <b>MIN</b><br>60<br>60 | MAX<br>-<br>-<br>-                           | V<br>V<br>NA                  |  |
| Collector -Emitter Voltage<br>Collector -Base Voltage<br>Emitter-Base Voltage  | VCEO*<br>VCBO<br>VEBO<br>ICBO                                    | IC=10mA,IB=0<br>IC=10uA.IE=0<br>IE=10uA, IC=0<br>VCB=50V, IE=0<br>Ta=150 deg C<br>VCB=50V, IE=0   | <b>MIN</b><br>60<br>60 | MAX<br>-<br>-<br>10<br>10                    | V<br>V<br>NA<br>uA            |  |
| Collector -Emitter Voltage<br>Collector -Base Voltage<br>Emitter-Base Voltage<br>Collector-Cut off Current   | VCEO*<br>VCBO<br>VEBO<br>ICBO                                    | IC=10mA,IB=0<br>IC=10uA.IE=0<br>IE=10uA, IC=0<br>VCB=50V, IE=0<br>Ta=150 deg C<br>VCB=50V, IE=0<br>VCE=30V, VBE=0.5V  | <b>MIN</b><br>60<br>60 | MAX<br>-<br>-<br>10<br>10<br>50              | V<br>V<br>nA<br>uA            |  |
| Collector -Emitter Voltage<br>Collector -Base Voltage<br>Emitter-Base Voltage<br>Collector-Cut off Current<br>Base Current   | VCEO*<br>VCBO<br>VEBO<br>ICBO<br>ICEX<br>IB                      | IC=10mA,IB=0<br>IC=10uA.IE=0<br>IE=10uA, IC=0<br>VCB=50V, IE=0<br>Ta=150 deg C<br>VCB=50V, IE=0<br>VCE=30V, VBE=0.5V<br>VCE=30V, VBE=0.5V                     | <b>MIN</b><br>60<br>60 | MAX<br>-<br>-<br>10<br>10<br>50<br>50        | V<br>V<br>nA<br>uA<br>nA      |  |
| Collector -Emitter Voltage<br>Collector -Base Voltage<br>Emitter-Base Voltage<br>Collector-Cut off Current<br>Base Current   | VCEO*<br>VCBO<br>VEBO<br>ICBO                                    | IC=10mA,IB=0<br>IC=10uA.IE=0<br>IE=10uA, IC=0<br>VCB=50V, IE=0<br>Ta=150 deg C<br>VCB=50V, IE=0<br>VCE=30V, VBE=0.5V<br>VCE=30V, VBE=0.5V<br>IC=150mA,IB=15mA | <b>MIN</b><br>60<br>60 | MAX<br>-<br>-<br>10<br>10<br>50<br>50<br>0.4 | V<br>V<br>nA<br>uA<br>nA<br>V |  |
| DESCRIPTION<br>Collector -Emitter Voltage<br>Collector -Base Voltage<br>Emitter-Base Voltage<br>Collector-Cut off Current<br>Base Current<br>Collector Emitter Saturation Voltage<br>Base Emitter Saturation Voltage | VCEO*<br>VCBO<br>VEBO<br>ICBO<br>ICBO<br>ICEX<br>IB<br>VCE(Sat)* | IC=10mA,IB=0<br>IC=10uA.IE=0<br>IE=10uA, IC=0<br>VCB=50V, IE=0<br>Ta=150 deg C<br>VCB=50V, IE=0<br>VCE=30V, VBE=0.5V<br>VCE=30V, VBE=0.5V                     | <b>MIN</b><br>60<br>60 | MAX<br>-<br>-<br>10<br>10<br>50<br>50        | V<br>V<br>nA<br>uA<br>nA      |  |

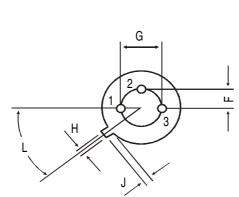
| J               | ( ) | IC=500mA,IB=50mA  | -       | 2.6     | V |
|-----------------|-----|-------------------|---------|---------|---|
|                 |     |                   | 2N2906A | 2N2907A |   |
| DC Current Gain | hFE | IC=0.1mA,VCE=10V  | >40     | >75     |   |
|                 |     | IC=1mA,VCE=10V    | >40     | >100    |   |
|                 |     | IC=10mA,VCE=10V   | >40     | >100    |   |
|                 |     | IC=150mA,VCE=10V* | 40-120  | 100-300 |   |
|                 |     | IC=500mA,VCE=10V* | >40     | >50     |   |

| DESCRIPTION             | SYMBOL | TEST CONDITION                  | MIN | MAX   | UNIT |
|-------------------------|--------|---------------------------------|-----|-------|------|
| DYNAMIC CHARACTERISTICS |        |                                 |     |       |      |
| Transition Frequency    | ft **  | ft ** IC=50mA, VCE=20V,f=100MHz |     | - MHz |      |
| Out-Put Capacitance     | Cob    | VCB=10V, IE=0,f=100kHz          | -   | 8.0   | pF   |
| Input Capacitance       | Cib    | VBE=2V, IC=0, f=100kHz          | -   | 30    | pF   |
| Switching Time          |        |                                 |     |       |      |
| Delay time              | td     | IC=150mA,IB1=15mA               | -   | 10    | ns   |
| Rise time               | tr     | VCC=30V                         | -   | 40    | ns   |
| Turn-On Time            | ton    |                                 |     | 45    | ns   |
| Storage time            | ts     | IC=150mA, IB1=IB2=15mA          | -   | 80    | ns   |
| Fall time               | tf     | VCC=6V                          | -   | 30    | ns   |
| Turn-Off Time           | toff   |                                 | -   | 100   | ns   |

\*\*ft is defined as the frequency at which \hfe/ extrapolates to unity

# **TO-18 Metal Can Package**





|         | DIM | MIN    | MAX  |  |
|---------|-----|--------|------|--|
| A<br>B  | Α   | 5.24   | 5.84 |  |
|         | В   | 4.52   | 4.97 |  |
|         | С   | 4.31   | 5.33 |  |
|         | D   | 0.40   | 0.53 |  |
|         |     | —      | 0.76 |  |
| Ë.      |     | —      | 1.27 |  |
| in<br>π |     | —      | 2.97 |  |
| ns      |     | 0.91   | 1.17 |  |
| nsic    | J   | 0.71   | 1.21 |  |
| limi    | K   | 12.70  |      |  |
| All     | L   | 45 DEG |      |  |
|         |     |        |      |  |



PIN CONFIGURATION 1. EMITTER 2. BASE 3. COLLECTOR

# Packing Detail

| PACKAGE | STANDARD PACK |                | INNER CARTON BOX |      | OUTER CARTON BOX  |       |        |
|---------|---------------|----------------|------------------|------|-------------------|-------|--------|
|         | Details       | Net Weight/Qty | Size             | Qty  | Size              | Qty   | Gr Wt  |
| T0-18   | 1K/polybag    | 350 gm/1K pcs  | 3" x 7.5" x 7.5" | 5.0K | 17" x 15" x 13.5" | 80.0K | 34 kgs |

Notes

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Data Sheet